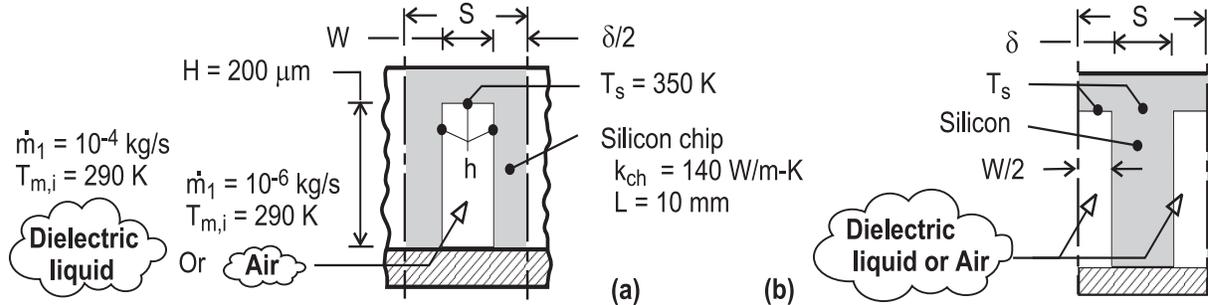


## PROBLEM 8.111

**KNOWN:** Chip and cooling channel dimensions. Channel flow rate and inlet temperature. Temperature of chip at base of channel.

**FIND:** (a) Outlet temperature and chip power dissipation for dielectric liquid, (b) Outlet temperature and chip power dissipation for air.

**SCHEMATIC:**



**ASSUMPTIONS:** (1) Applicability of Eq. 8.34, (2) Flow may be approximated as fully developed and channel walls as isothermal for purposes of estimating the convection coefficient, (3) One-dimensional conduction along the channel side walls, (4) Adiabatic condition at end of side walls, (5) Heat dissipation is exclusively through fluid flow in channels, (6) Constant properties.

**PROPERTIES:** Prescribed. Dielectric liquid:  $c_p = 1050 \text{ J/kg}\cdot\text{K}$ ,  $k = 0.065 \text{ W/m}\cdot\text{K}$ ,  $\mu = 0.0012 \text{ N}\cdot\text{s/m}^2$ ,  $\text{Pr} = 15$ . Air:  $c_p = 1007 \text{ J/kg}\cdot\text{K}$ ,  $k = 0.0263 \text{ W/m}\cdot\text{K}$ ,  $\mu = 185 \times 10^{-7} \text{ N}\cdot\text{s/m}^2$ ,  $\text{Pr} = 0.707$ .

**ANALYSIS:** (a) The channel side walls act as fins, and a *unit* channel/sidewall combination is shown in schematic (a), where  $\delta = S - W = 150 \mu\text{m}$ . Alternatively, the unit cell may be represented in terms of a single fin of thickness  $\delta$ , as shown in schematic (b). The thermal resistance of the unit cell may be obtained from the expression for a fin array, Eq. (3.108),  $R_{t,o} = (\eta_o h A_t)^{-1}$ , where  $A_t = A_f + A_b = L (2H + W) = 4.5 \times 10^{-6} \text{ m}^2$ . With  $A_c = H \times W = 10^{-8} \text{ m}^2$  and  $D_h = 4 A_c / (2H + W) = 8 \times 10^{-5} \text{ m}$ , the Reynolds number is  $\text{Re}_D = \rho u_m D_h / \mu = \dot{m}_1 D_h / A_c \mu = 667$ . Hence, the flow is laminar, and assuming fully developed conditions throughout a channel with uniform surface temperature, Table 8.1 yields

$$\text{Nu}_D = 4.44. \text{ Hence, } h = \frac{k}{D_h} \text{Nu}_D = \frac{0.065 \text{ W/m}\cdot\text{K} \times 4.44}{8 \times 10^{-5} \text{ m}} = 3608 \text{ W/m}^2 \cdot \text{K}$$

With  $m = (2h/k_{ch}\delta)^{1/2} = 586 \text{ m}^{-1}$  and  $mH = 0.117$ , the fin efficiency is

$$\eta_f = \frac{\tanh mH}{mH} = \frac{0.1167}{0.117} = 0.995$$

and the overall surface efficiency is

$$\eta_o = 1 - \frac{A_f}{A_t} (1 - \eta_f) = 1 - \frac{4.0 \times 10^{-6}}{4.5 \times 10^{-6}} (1 - 0.995) = 0.996.$$

The thermal resistance of the unit cell is then

$$R_{t,o} = (\eta_o h A_t)^{-1} = \left( 0.996 \times 3608 \text{ W/m}^2 \cdot \text{K} \times 4.5 \times 10^{-6} \text{ m}^2 \right)^{-1} = 61.9 \text{ K/W}$$

The outlet temperature follows from Eq. (8.45b),

$$T_{m,o} = T_s - (T_s - T_{m,i}) \exp \left( -\frac{1}{\dot{m}_1 c_p R_{t,o}} \right) = 350 \text{ K}$$

Continued ...

**PROBLEM 8.111 (Cont.)**

$$-(60\text{K}) \exp\left(-\frac{1}{10^{-4} \text{ kg/s} \times 1050 \text{ J/kg} \cdot \text{K} \times 61.9 \text{ K/W}}\right) = 298.6\text{K} \quad <$$

The heat rate per channel is then

$$q_1 = \dot{m}_1 c_p (T_{m,o} - T_{m,i}) = 10^{-4} \text{ kg/s} \times 1050 \text{ J/kg} \cdot \text{K} \times 8.6 \text{ K} = 0.899 \text{ W}$$

and the chip power dissipation is

$$q = Nq_1 = 50 \times 0.899 \text{ W} = 45.0 \text{ W} \quad <$$

(b) With  $\dot{m}_1 = 10^{-6} \text{ kg/s}$ ,  $Re_D = \dot{m}_1 D_h / A_c \mu = 432$  and the flow is laminar. Hence, with  $Nu_D = 4.44$ ,

$$h = \frac{k}{D_h} Nu_D = \frac{0.0263 \text{ W/m} \cdot \text{K} \times 4.44}{8 \times 10^{-5} \text{ m}} = 1460 \text{ W/m}^2 \cdot \text{K}$$

With  $m = (2h/k_{ch}\delta)^{1/2} = 373 \text{ m}^{-1}$  and  $mH = 0.0746$ , the fin efficiency is

$$\eta_f = \frac{\tanh mH}{mH} = \frac{0.0744}{0.0746} = 0.998$$

and the overall surface efficiency is

$$\eta_o = 1 - \frac{A_f}{A_t} (1 - \eta_f) = 1 - \frac{4.0 \times 10^{-6}}{4.5 \times 10^{-6}} (1 - 0.998) = 0.998$$

Hence,  $R_{t,o} = (\eta_o h A_t)^{-1} = \left(0.998 \times 1460 \text{ W/m}^2 \cdot \text{K} \times 4.5 \times 10^{-6} \text{ m}^2\right)^{-1} = 153 \text{ K/W}$

The outlet temperature is then

$$T_{m,o} = T_s - (T_s - T_{m,i}) \exp\left(-\frac{1}{\dot{m}_1 c_p R_{t,o}}\right) = 350\text{K}$$

$$-(60\text{K}) \exp\left(-\frac{1}{10^{-6} \text{ kg/s} \times 1007 \text{ J/kg} \cdot \text{K} \times 153 \text{ K/W}}\right) = 349.9 \text{ K} \quad <$$

$$q_1 = \dot{m}_1 c_p (T_{m,o} - T_{m,i}) = 10^{-6} \text{ kg/s} \times 1007 \text{ J/kg} \cdot \text{K} \times 59.9 \text{ K} = 0.060 \text{ W}$$

$$q = Nq_1 = 3.02 \text{ W} \quad <$$

**COMMENTS:** (1) For laminar flow in the channels, there is a clear advantage to using the dielectric liquid instead of air. (2) The prescribed channel geometry is by no means optimized, and the number of fins should be increased by reducing  $S$ . Also, channel dimensions and/or flow rates could be increased to achieve turbulent flow and hence much larger values of  $h$ . (3) With  $L/D_h = 125$  and  $(L/D_h)_{fd} \approx 0.05 Re_D Pr = 500$  for the dielectric liquid, fully developed flow is not achieved and its assumption yields a conservative (under) estimate of the convection coefficient. The coefficient is also underestimated by using a Nusselt number that presumes heat transfer from all four (rather than three) surfaces of a channel.